



#### 80V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>C</sub> = +25°C
80V	17mΩ @ V <sub>GS</sub> = 10V	65A
	21mΩ @ V <sub>GS</sub> = 4.5V	59A

### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

PowerDI5060-8

- Synchronous Rectifier
- Backlighting
- Power Management Functions
- DC-DC Converters

# **Features**

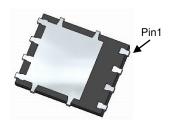
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

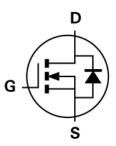
- Case: PowerDI<sup>®</sup> 5060-8
- Case Material: Molded Plastic, "Green" Molding Compound;
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
   Solderable per MIL-STD-202, Method 208 <sup>3</sup>
- Weight: 0.097 grams (Approximate)



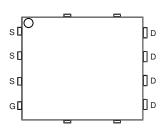




**Bottom View** 



Internal Schematic



Top View Pin Configuration

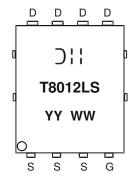
#### Ordering Information (Note 4)

Part Number	Case	Packaging	
DMT8012LPS-13	PowerDI5060-8	2,500 / Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# Marking Information



T8012LS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 17 = 2017)
WW = Week Code (01 to 53)

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# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		$V_{DSS}$	80	V
Gate-Source Voltage		$V_{GSS}$	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 5)	$T_A = +25$ °C $T_A = +70$ °C	I <sub>D</sub>	9 7.2	А
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 6)	$T_C = +25$ °C $T_C = +70$ °C	I <sub>D</sub>	65 51	А
Maximum Continuous Body Diode Forward Current (Note 6)	Is	80	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	80	Α	
Avalanche Current, L=0.1mH		I <sub>AS</sub>	11.6	A
Avalanche Energy, L=0.1mH		E <sub>AS</sub>	10.2	mJ

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	$P_{D}$	2.1	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\theta JA}$	56	°C/W
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		$P_{D}$	113	W
Thermal Resistance, Junction to Case (Note 6)		R <sub>0</sub> JC	1.1	°C/W
Operating and Storage Temperature Range		$T_{J_i} T_{STG}$	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	80	-	-	V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	1	μA	$V_{DS} = 64V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±100	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	$V_{GS(TH)}$	1	1.3	3	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance		-	14	17	mΩ	$V_{GS} = 10V, I_D = 12A$	
Static Drain-Source On-Nesistance	R <sub>DS(ON)</sub>	-	16.5	21	11177	$V_{GS} = 4.5V, I_D = 6A$	
Diode Forward Voltage	$V_{SD}$	-	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	-	1,949	-		V 40V V 0V	
Output Capacitance	Coss	-	177	-	pF	$V_{DS} = 40V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Reverse Transfer Capacitance	C <sub>rss</sub>	-	10	-			
Gate Resistance	$R_g$	-	0.7	-	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	-	15	-			
Total Gate Charge (V <sub>GS</sub> = 10V)	$Q_g$	-	34	-	nC	Vps = 40V. lp = 12A	
Gate-Source Charge	Qgs	-	6	-	110	V <sub>DS</sub> = 40V, I <sub>D</sub> = 12A	
Gate-Drain Charge	$Q_{gd}$	-	4.5	-			
Turn-On Delay Time	t <sub>D(ON)</sub>	-	4.9	-		$V_{DD} = 40V, V_{GS} = 10V,$ $I_{D} = 12A, R_{G} = 1.6\Omega$	
Turn-On Rise Time	t <sub>R</sub>	-	3.8	-	ns		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	-	16.5	-	TIS		
Turn-Off Fall Time	t <sub>F</sub>	-	3.5	-			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	-	30.2	-	ns	I_ 10A di/dt 100A/va	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	-	34.6	-	nC	I <sub>F</sub> = 12A, di/dt = 100A/μs	

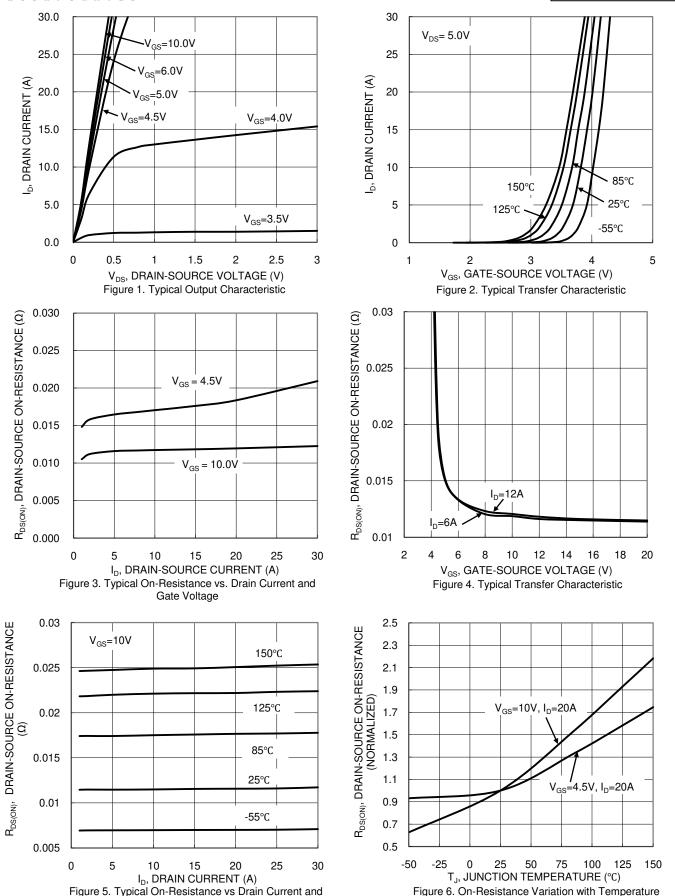
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

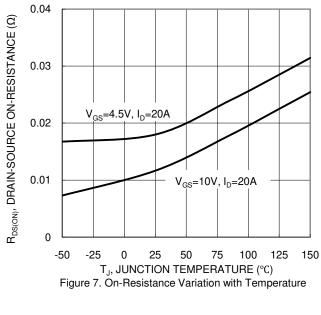


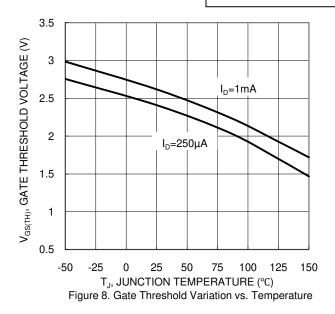


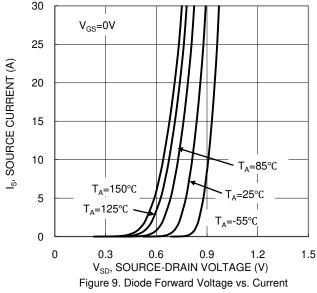
Temperature

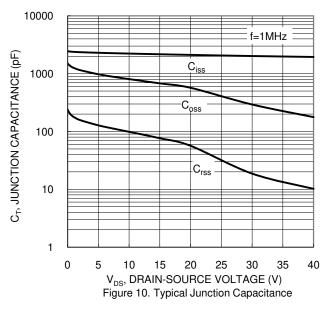


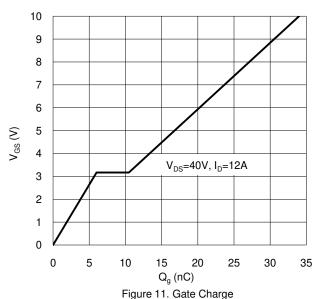












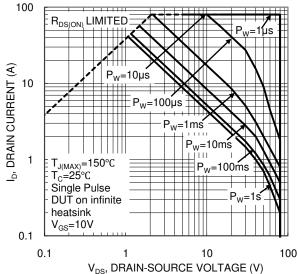
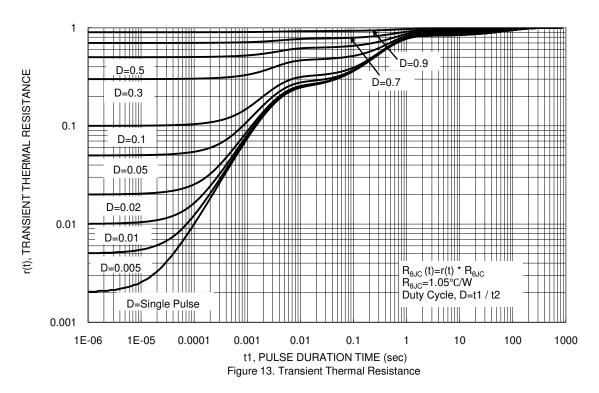


Figure 12. SOA, Safe Operation Area



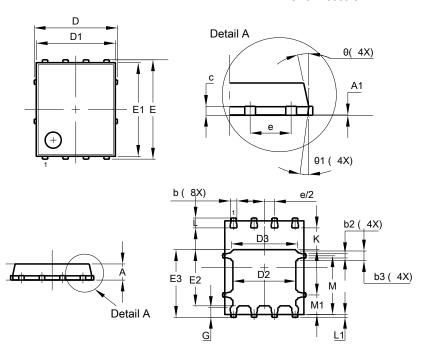




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8

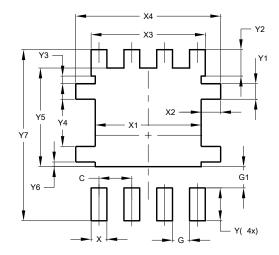


PowerDI5060-8					
Dim	Min Max		Тур		
Α	0.90	1.10	1.00		
<b>A</b> 1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
c D	0.230	0.330	0.277		
	5.15 BSC				
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	•	3.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8



Dimensions	Value (in mm)			
C	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
<b>Y</b> 7	6.610			



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